

Surface Mount Ultrafast Plastic Rectifier


DO-214AA (SMB)
FEATURES

- Glass passivated chip junction
- Ideal for automated placement
- Ultrafast recovery times for high efficiency
- Low forward voltage, low power losses
- High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Solder dip 260 °C, 40 s
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC


RoHS
COMPLIANT

TYPICAL APPLICATIONS

For use in high frequency rectification and freewheeling application in switching mode converters and inverters for consumer, computer, automotive and telecommunication.

MECHANICAL DATA

Case: DO-214AA (SMB)

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

Polarity: Color band denotes cathode end

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2.0 A
V_{RRM}	50 V to 200 V
I_{FSM}	50 A
t_{rr}	20 ns
V_F	0.90 V
$T_J \text{ max.}$	150 °C

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	SYMBOL	ES2A	ES2B	ES2C	ES2D	UNIT
Device marking code		EA	EB	EC	ED	
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	150	200	V
Maximum RMS voltage	V_{RMS}	35	70	105	140	V
Maximum DC blocking voltage	V_{DC}	50	100	150	200	V
Maximum average forward rectified current at $T_L = 110 \text{ °C}$	$I_{F(AV)}$	2.0				A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I_{FSM}	50				A
Operating junction and storage temperature range	T_J, T_{STG}	- 55 to + 150				°C

ELECTRICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER	TEST CONDITIONS	SYMBOL	ES2A	ES2B	ES2C	ES2D	UNIT
Maximum instantaneous forward voltage ⁽¹⁾	2.0 A	V_F	0.90				V
Maximum DC reverse current at rated DC blocking voltage		I_R		10			μA
				350			

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS	SYMBOL	ES2A	ES2B	ES2C	ES2D	UNIT
Max. reverse recovery time	I _F = 0.5 A, I _R = 1.0 A, I _{rr} = 0.25 A	t _{rr}		20			ns
Maximum reverse recovery time	I _F = 2.0 A, V _R = 30 V, di/dt = 50 A/μs, I _r = 10 % I _{RM}	t _{rr}		30 50			ns
Maximum stored charge	I _F = 2.0 A, V _R = 30 V, di/dt = 50 A/μs, I _r = 10 % I _{RM}	Q _{rr}		10 25			nC
Typical junction capacitance	4.0 V, 1 MHz	C _J		18			pF

Note:

(1) Pulse test: 300 ms pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	ES2A	ES2B	ES2C	ES2D	UNIT	
Typical thermal resistance ⁽¹⁾	R _{θJA} R _{θJL}		75 20			°C/W	

Note:

(1) Units mounted on P.C.B. 5.0 x 5.0 mm (0.013 mm thick) land areas

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
ES2D-E3/52T	0.096	52T	750	7" diameter plastic tape and reel	
ES2D-E3/5BT	0.096	5BT	3200	13" diameter plastic tape and reel	
ES2DHE3/52T ⁽¹⁾	0.096	52T	750	7" diameter plastic tape and reel	
ES2DHE3/5BT ⁽¹⁾	0.096	5BT	3200	13" diameter plastic tape and reel	

Note:

(1) Automotive grade AEC Q101 qualified

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

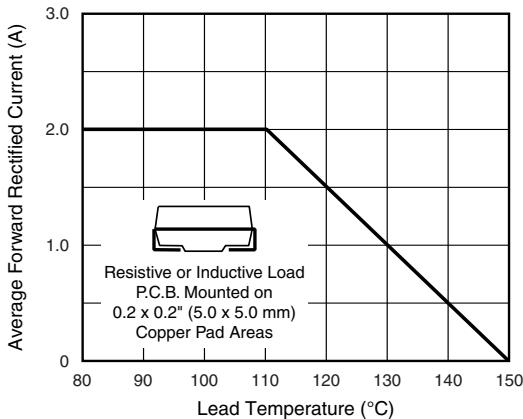


Figure 1. Maximum Forward Current Derating Curve

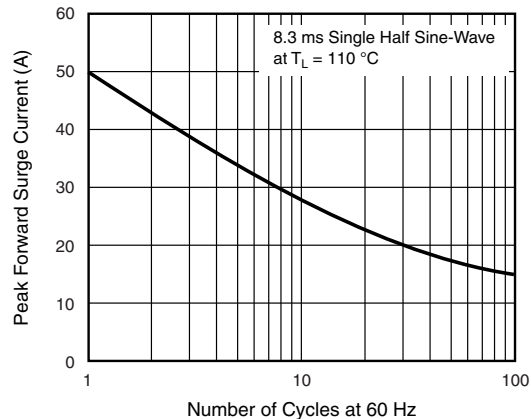


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current

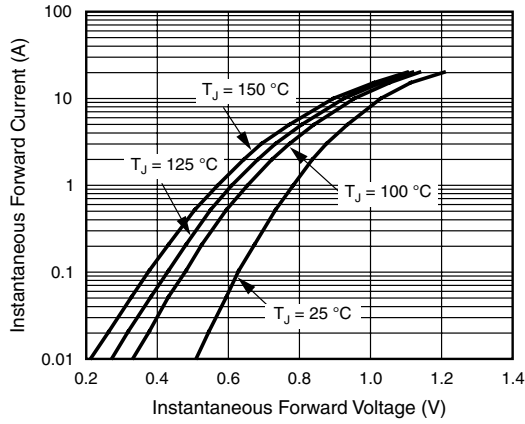


Figure 3. Typical Instantaneous Forward Characteristics

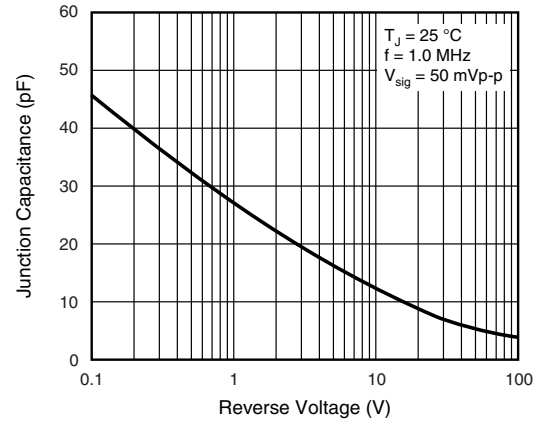


Figure 5. Typical Junction Capacitance

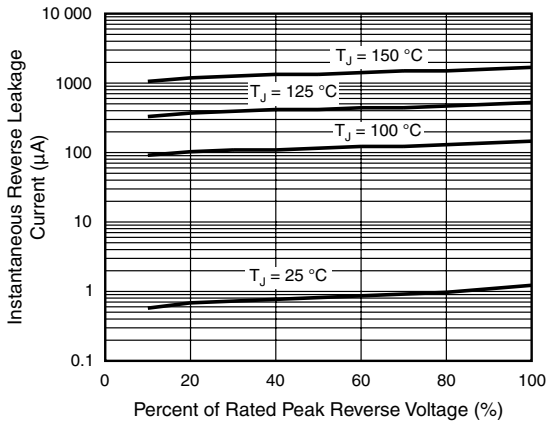


Figure 4. Typical Reverse Leakage Characteristics

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

